An OTFT-driven rollable OLED display

Makoto Noda
Norihito Kobayashi
Mao Katsuhara
Akira Yumoto
Shinichi Ushikura
Ryouichi Yasuda
Nobukazu Hirai
Gen Yukawa
Iwao Yagi
Kazumasa Nomoto
Tetsuo Urabe

Abstract — An 80-µm-thick rollable AMOLED display driven by an OTFT is reported. The display was developed so as to berollable in one direction with an integrated OTFT gate driver circuit. It was successfully operated by an originally developed organic semiconductor, a peri-xanthenoxanthene derivative. The display retained its initial electrical properties and picture quality even after being subjected to 1000 cycles of a roll-up-and-release test with a radius of 4 mm.

Keywords — Organic TFT, rollable display, OLED display.

DOI # 10.1889/JSID19.4.316

1 Introduction

Flexible active-matrix organic light-emitting-diode (AMOLED) displays have been receiving considerable attention because they are mechanically robust, lightweight, and thin, besides featuring excellent display properties. A rollable AMOLED display is attractive as a portable display device: The fact that it can be stored in a small space in a rolled-up condition greatly enhances its portability. Even though several types of flexible AMOLED displays have been developed over the past several years,1–11 no rollable AMOLED displays have been reported to date. Organic TFT (OTFT) backplanes are a promising candidate for rollable displays because they are made of mechanically flexible organic materials. An OTFT has reportedly been successfully operated with a submillimeter bending radius.12 Furthermore, OTFTs can be fabricated using solution processes, allowing a vacuum-free short-turn-around-time printing process. OLEDs are also suitable for rollable displays because they are all-solid-state display devices. Thus, OTFTs and OLEDs are conducive to being used in rollable displays. In this paper, we report on an OTFT-driven rollable OLED display.13 An originally developed organic semiconductor, a peri-xanthenoxanthene (PXX) derivative,14 was used for the active layer of the OTFT backplane, which improved the performance of OTFT, yielding mobility and subthreshold swing values of 0.4 cm²/V-sec and 0.6 V/decade, respectively. An OTFT gate driver circuit was integrated into the backplane so that the display could be rolled up in one direction. The display showed no degradation in electrical properties or picture quality after 1000 roll-up-and-release cycles with a radius of 4 mm.

2 The rollable AMOLED display

Figures 1(a) and 1(b) show photographs of our newly developed OTFT-driven rollable AMOLED display operated in a flat and rolled-up condition, respectively. The display, with its thickness of only 80 µm, is so flexible that it can operate without failure in a rolled-up condition with a radius of 4 mm. Figure 2 shows the layout and circuit diagram of the display. In the 4.1-in. FWQVGA display, 240 × RGB signal

FIGURE 1 — Photographs of our rollable OTFT-driven OLED display (a) in a flat condition and (b) in a rolled-up condition with r = 4 mm.
lines are parallel to the roll-up direction, while 432 scanning lines are perpendicular to it. External source driver ICs for supplying signal voltages \( V_{\text{sig}} \) are employed. However, no external gate driver ICs are mounted on the display because an OTFT gate driver circuit supplying gate pulses \( V_{\text{scan}} \) is integrated on the side of the pixels, allowing the display to be rolled up. The inset of Fig. 2 shows a schematic diagram of the pixel circuit, which has a standard two-transistor one-capacitor architecture. The circuit parameters are designed so as to be operable at a frame rate of 60 Hz.

3 Flexible OTFT backplane

Figure 3 shows a schematic cross section of the display. We employed a stacked top-emission structure, which is advantageous to achieve a high resolution owing to the small footprint of a pixel in contrast to a side-by-side bottom-emission structure. The 20-µm-thick flexible substrate, on which OTFTs and OLEDs were integrated, and a 25-µm-thick cover film were employed. The resultant thickness of the display was 80 µm, which enhanced its flexibility.

The OTFT in the backplane had an inverted staggered-type structure with a channel length of 5 µm. First, the gate was formed by vacuum deposition and patterned by photolithography. Then, an originally developed gate insulator (GI) consisting of a blend of polyvinyl phenol with octadecyltrichloro-silan (PVP-OTS)\textsuperscript{15} was formed by spin-coating. The gate insulator had a typical thickness of 400 nm and a relative dielectric constant of \( \varepsilon = 4 \). An originally developed organic semiconductor (OSC), a PXX derivative, was employed as an active layer. The PXX derivative is stable under ambient conditions and thermal stress because the reactive sites of the molecule are passivated by oxygen atoms, which suppresses the degradation of OTFT performance during the integration. After the deposition and patterning of the active layer and S/D metal electrodes, fluorinated polymer as passivation (PSV) and a conventional photopatternable resist as planarization layers (PLN) were formed by spin-coating. After the fabrication of through-holes, anode electrodes (AND) tied electrically to the drain of the drive OTFT were formed and the emission area was defined by the pixel-defining layer (PDL). As described above, a low-temperature solution process was employed for our OTFT backplane.\textsuperscript{16} Figure 4 shows the integration flow of the OTFT backplane and the process temperature at each fabrication step. The maximum process temperature throughout the integration was 180°C. All the insulators consisted of mechanically soft polymers, allowing the display to be flexible and they were fabricated by a solution process.

Figure 5 shows the top view of a pixel in the OTFT backplane. A dense integration with a pixel pitch of 210 µm was achieved, which corresponds to a resolution of 121 ppi.
4 Properties of rollable OLED display

Figure 6 shows a photograph of our 4.1-in. full-color OTFT-driven rollable OLED display, and Table 1 summarizes its specifications. The display was successfully driven by a PXX-TFT backplane. Not only still images, but also moving images at a frame rate of 60 Hz could be displayed.

<table>
<thead>
<tr>
<th>Display Size</th>
<th>4.1-in.Wide</th>
</tr>
</thead>
<tbody>
<tr>
<td>Number of Pixels</td>
<td>$432 \times RGB \times 240$ (FWQVGA)</td>
</tr>
<tr>
<td>Pixel Size</td>
<td>$210 , \mu m \times 210 , \mu m$</td>
</tr>
<tr>
<td>Resolution</td>
<td>121 ppi</td>
</tr>
<tr>
<td>Number of Colors</td>
<td>16,777,216</td>
</tr>
<tr>
<td>Peak Luminance</td>
<td>$&gt; 100 , cd/m^2$</td>
</tr>
<tr>
<td>Contrast Ratio</td>
<td>$&gt; 1000:1$</td>
</tr>
<tr>
<td>Operation Scheme</td>
<td>2T-1C Voltage Programming</td>
</tr>
<tr>
<td>Scan Voltage</td>
<td>20 Vp-p</td>
</tr>
<tr>
<td>Signal Voltage</td>
<td>$&lt; 10 , Vp-p$</td>
</tr>
<tr>
<td>$V_{cc} - V_{cath}$</td>
<td>20 V</td>
</tr>
<tr>
<td>Thickness</td>
<td>80 $\mu m$</td>
</tr>
<tr>
<td>Bending Radius</td>
<td>4 mm</td>
</tr>
</tbody>
</table>

5 Characterization of OTFT backplane

In this section, we discuss the properties of our newly developed PXX-TFT backplane with respect to its performance, driving voltage of the display, uniformity, and electrical sta-

![Figure 7](image7.png)

**TABLE 1** — Specifications of the display.

**TABLE 2** — Comparison of electrical properties of pentacene TFT and PXX TFT.

<table>
<thead>
<tr>
<th>Active layer</th>
<th>$\mu_{FE}$ (cm$^2$/V·sec)</th>
<th>S.S. (V/dec.)</th>
</tr>
</thead>
<tbody>
<tr>
<td>pentacene</td>
<td>$\sim 0.1$</td>
<td>1.2</td>
</tr>
<tr>
<td>PXX derivative</td>
<td>$\sim 0.4$</td>
<td>0.6</td>
</tr>
</tbody>
</table>

**FIGURE 7** — (a) Output and (b) transfer characteristics of the drive TFT.
bility under DC bias stress. These characteristics of the PXX-TFT backplane are compared with our pentacene-TFT backplane. The PXX derivative led to improved performance, lower voltage driving of the display, and higher stability under DC bias-stress as compared to the pentacene-TFT backplane. The uniform on-current characteristics of the PXX TFT were comparable to those of the pentacene TFT.

5.1 Performance

Typical output and transfer characteristics of the drive TFT in the display are shown in Figs. 7(a) and 7(b). In the PXX TFT, the field-effect mobility ($\mu_{FE}$) and subthreshold wing ($S.S.$) were 0.4 cm$^2$/V-sec and 0.6 V/decade, respectively. For a comparison of electrical characteristics, the transfer characteristics of a pentacene TFT in the backplane fabricated by the same process are also plotted in Fig. 7(b). Using the PXX derivative improved the performance of the OTFT not only in terms of the field-effect mobility, but also the subthreshold swing (see Table 2). This indicates that the current-contrast ratio of the PXX TFT is higher than that of the pentacene TFT at the same driving voltage. The driving voltage of the display with PXX-TFT backplane could be lower than that with pentacene-TFT backplane, as described in the next section.

5.2 Driving voltage of the display

Figure 8 shows gamma curves, i.e., the relationship between display luminance and signal voltage, of the display with PXX-TFT backplane and, as a reference, of the pentacene-TFT driven OLED display, which was demonstrated in our previous paper.\textsuperscript{16} The display luminance from black to white level was well controlled by the signal voltage. The display could be driven at a signal voltage of 7 V to obtain a contrast ratio of 1000:1 with a peak luminance of 100 cd/m$^2$. The PXX-TFT backplane reduced the signal voltage by 30% with respect to the pentacene-TFT backplane for the same luminance and contrast ratio of display. This is due to the higher current-contrast ratio of the PXX-TFT backplane as compared to that of the pentacene-TFT backplane [see Fig. 7(b)]. Thus, the PXX-TFT backplane is effective in reducing power consumption.
5.3 Uniformity

Figure 9 shows the transfer characteristics of 47 OTFTs with a channel length of 5 \( \mu \)m after integration of backplane. Uniform characteristics were achieved for the OTFTs, with a standard deviation of on-current of less than 5%, which is comparable to that of the pentacene TFT.9

Figure 10 shows an optical micrograph of emission from the pixels in the display. The luminance of each pixel was uniform over the short range, which is strongly supported by the uniform characteristics of the PXX TFT featuring the combination of a newly developed PXX derivative and an originally developed PVP-OTS gate insulator.

5.4 Bias-stress instability

A DC bias-stress test was performed on the PXX TFT after integration, under ambient conditions with an applied voltage of \( V_{GS} = -12 \) V and \( V_{DS} = -12 \) V.

Figure 11 shows transfer characteristics of the PXX TFT before and after applying the bias stress. There was no significant change in transfer characteristics upon applying a DC bias-stress for 1500 sec. Figure 12 shows the time dependence of \( V_{th} \) in PXX TFT and pentacene TFT as reference, fabricated using the same process. The variation in \( V_{th} \) in PXX TFT was negligibly small during the DC bias-stress test, while the DC bias-stress after 1500 sec caused a negative \( V_{th} \) shift of 0.1 V in pentacene TFT. These results indicate that the electrical stability of PXX TFT under bias stress is better than that of pentacene TFT, which is due to the improved interface between the active layer and gate insulator.

6 OTFT performance in bending state

It has been reported that the electrical characteristics of the flexible OTFT changed in a bending state. The change in electrical properties depended on the bending direction, bending radius, and device structure.12,17 We have measured the mobility \( (\mu) \) in the OTFT of our display while systematically varying the bending radius from 3 to 12 mm.

Figure 13 shows the dependence of the normalized mobility \( (\mu/\mu_0) \) on the bending radius of an OTFT in the display, where \( \mu_0 \) is the mobility measured in a flat state. In the case of inward bending, the mobility increased with decreasing bending radius. By contrast, the mobility decreased with decreasing bending radius in outward bending. The change in mobility was less than 5% with a bending radius of 3 mm, under both inward and outward bending. This change was reversible (see Fig. 14). Measurement of
the mobility in a flat state was followed by measurement in a bending state with a radius of 3 mm. This series of measurements was repeated three times, both for outward and inward bending. The results indicate that the OTFT backplane can operate stably under both inward and outward bending with a radius of 3 mm.

7 Cyclic bending test

The mechanical stability of the OTFTs in the display is discussed. Figure 15(a) shows the schematic cross section of the device that was used for the cyclic bending tests, and Fig. 15(b) shows the cyclic bending test procedure. The device was bent outward along a cylinder with a radius of 4 mm. Then, it was returned to its flat state. The OTFT characteristics were measured in the flat state during the cyclic bending test.

Figure 16 shows the transfer characteristics of the OTFT in the display, measured before and after 100,000 cycles of bending with a radius of 4 mm. The OTFT showed no significant change in transfer characteristics after the cyclic bending test. Figure 17 shows both the on- and off-current as a function of the number of bending cycles. The change in the on-current was 1% even after 100,000 cycles. The off-current did not exhibit any obvious increase either. These results indicate that our OTFT backplane can drive a rollable OLED display stably under cyclic mechanical stress.

8 Roll-up-and-release test

We have also explored the mechanical stability of the display in a roll-up-and-release test, as shown in Figs. 1(a) and 1(b). First, the display was rolled up along a cylinder with a radius of 4 mm. Then, it was released completely. This roll-up-and-release cycle was repeated 1000 times. Figure 18 shows gamma curves of the display measured before and after the test. The display showed no significant degradation in
gamma curves even after 1000 test cycles. This result indicates that neither the mobility of OTFT nor the efficiency of OLED changed during the test. The picture quality of the display after the test retained its initial state without additional defects, such as line defects, dark spots, or bright spots.

9 Conclusions

We have developed an OTFT-driven rollable OLED display with a thickness of 80 µm. The display was successfully operated by an OTFT with a newly developed organic semiconductor, a PXX derivative. By using this PXX derivative, the OTFT performance could be improved in terms of the field-effect mobility and subthreshold swing, as compared with a pentacene TFT. This led to lower voltage driving of the display and higher stability under DC bias-stress. The OTFT gate driver circuit was integrated into the backplane, which enabled the display to be rolled up. The display showed no degradation in electrical characteristics or picture quality after 1000 cycles of a 4-mm-radius roll-up-and-release test. The mechanical stability of our display is a direct function of the flexibility of the OTFT backplane consisting of mechanically soft organic materials. The present results indicate that our technology is promising for rollable displays.

Acknowledgments

The authors thank T. Sasaoka and T. Hirano for their kind suggestions in support of our project. The authors also thank N. Yoneya for technical advice regarding OTFT devices and T. Moriwaki for assistance with OLED fabrication.

References